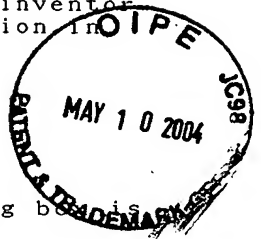


DECLARATION FOR PATENT APPLICATION

03S1184-1

As a below named inventor, I declare:

that I verily believe myself to be the original, first and sole (if only one individual inventor is listed below) or an original, first and joint inventor (if more than one individual inventor is listed below) of the invention in



SEMICONDUCTOR STRUCTURE, SEMICONDUCTOR DEVICE, AND METHOD AND APPARATUS FOR MANUFACTURING THE SAME

the specification of which is attached hereto unless the following be checked.

- ☐ was filed on _____ as United States Application or PCT International Application No. _____, and was amended on _____ (if applicable).

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information of which is material to patentability as defined in 37 CFR 1.56.

I hereby claim foreign priority benefits under 35 U.S.C. 119(a)-(d) or 365 (b) of any foreign application(s) for patent or inventor's certificate, or 35 U.S.C. 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below any foreign application for patent or inventor's certificate, or PCT International application having a filing date before that of the application on which priority is claimed:

<u>Country</u>	<u>Category</u>	<u>Application No.</u>	<u>Filing Date</u>	<u>Priority Claim</u>
Japan	Patent	2002-346806	November 29, 2002	Yes
Japan	Patent	2003-121772	April 25, 2003	Yes

I hereby appoint the registrants of Oblon, Spivak, McClelland, Maier & Neustadt, P.C., 1940 Duke Street, Alexandria, Virginia 22314, Customer No. 22850, or any one of them. Send correspondence to Oblon, Spivak, McClelland, Maier & Neustadt, P.C., 1940 Duke Street, Alexandria, Virginia 22314, Telephone No. (703) 413-3000.



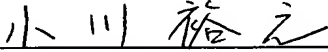
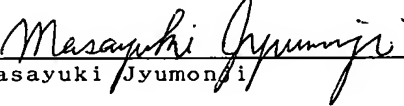
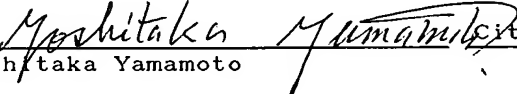
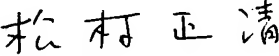
I declare further that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.



03S1184-1

DECLARATION FOR PATENT APPLICATION

I declare further that my citizenship, residence and mailing address are as stated below next to my name:

Inventor: (Signature)	Date	Residence and mailing address
 Masato Hiramatsu	Date: Dec. 12, 2003 Citizen of: Japan	c/o Advanced LCD Technologies Development Center Co., Ltd., 292, Yoshida-cho, Totsuka-ku, Yokohama-shi, Kanagawa-ken, Japan
 Yoshinobu Kimura	Date: Dec. 12, 2003 Citizen of: Japan	c/o Advanced LCD Technologies Development Center Co., Ltd., 292, Yoshida-cho, Totsuka-ku, Yokohama-shi, Kanagawa-ken, Japan
 Hiroyuki Ogawa	Date: Dec. 12, 2003 Citizen of: Japan	c/o Advanced LCD Technologies Development Center Co., Ltd., 292, Yoshida-cho, Totsuka-ku, Yokohama-shi, Kanagawa-ken, Japan
 Masayuki Jyumonji	Date: Dec. 12, 2003 Citizen of: Japan	c/o Advanced LCD Technologies Development Center Co., Ltd., 292, Yoshida-cho, Totsuka-ku, Yokohama-shi, Kanagawa-ken, Japan
 Yoshitaka Yamamoto	Date: Dec. 12, 2003 Citizen of: Japan	c/o Advanced LCD Technologies Development Center Co., Ltd., 292, Yoshida-cho, Totsuka-ku, Yokohama-shi, Kanagawa-ken, Japan
 Masakiyo Matsumura	Date: Dec. 12, 2003 Citizen of: Japan	c/o Advanced LCD Technologies Development Center Co., Ltd., 292, Yoshida-cho, Totsuka-ku, Yokohama-shi, Kanagawa-ken, Japan
	Date: Citizen of: Japan	
	Date: Citizen of: Japan	